

Ultrahigh-energy sodium ion capacitors enabled by enhanced intercalation
pseudocapacitance of self-standing $\text{Ti}_2\text{Nb}_2\text{O}_9/\text{CNF}$ anodes

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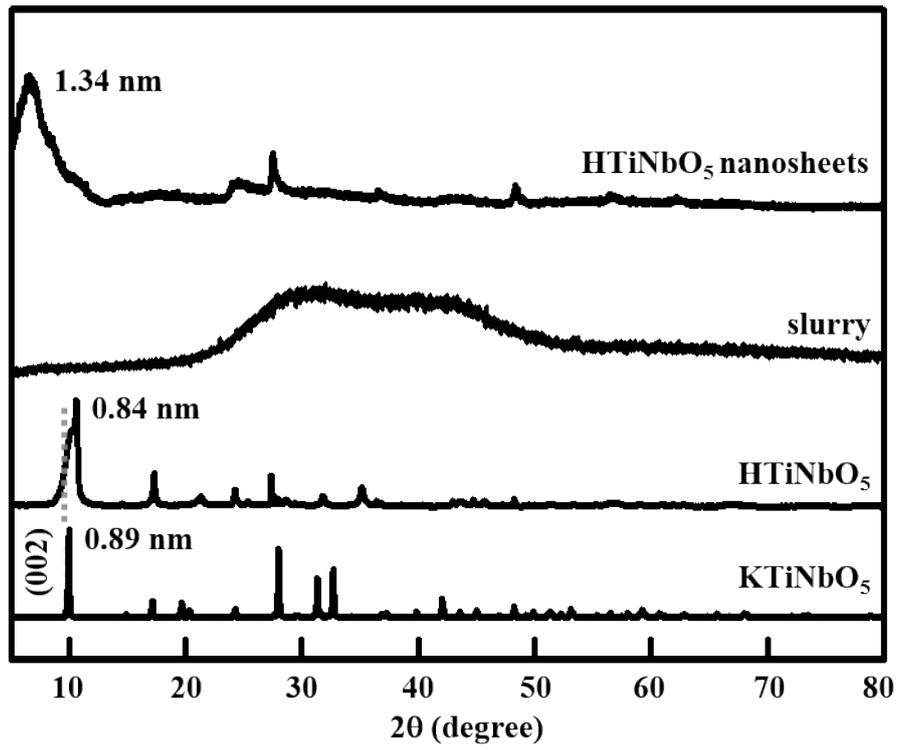


Fig. S1. XRD patterns of bulk KTiNbO₅, bulk HTiNbO₅, delaminated HTiNbO₅ slurry, and HTiNbO₅ nanosheets.

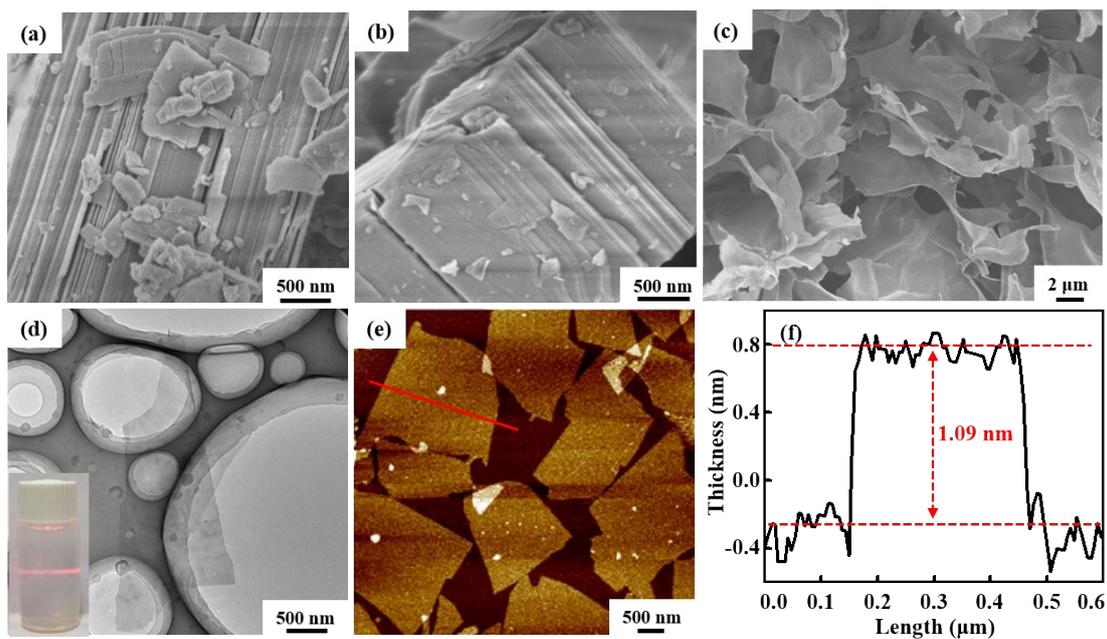


Fig. S2. FE-SEM images of bulk KTiNbO_5 (a), bulk HTiNbO_5 (b), HTiNbO_5 nanosheets (c), TEM image (inserted for the delaminated HTiNbO_5 nanosheets suspension) (d), AFM image (e), and the thickness profile (f) of the delaminated HTiNbO_5 nanosheets.

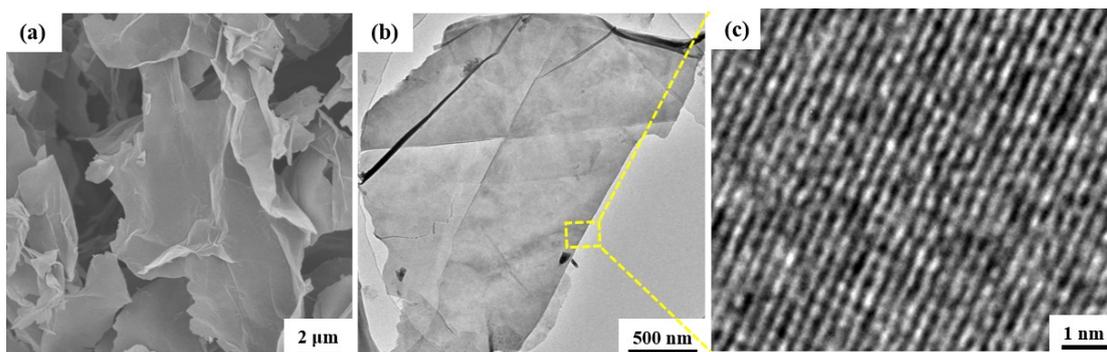


Fig. S3. SEM (a), TEM (b), and HRTEM (c) images of $\text{Ti}_2\text{Nb}_2\text{O}_9$.

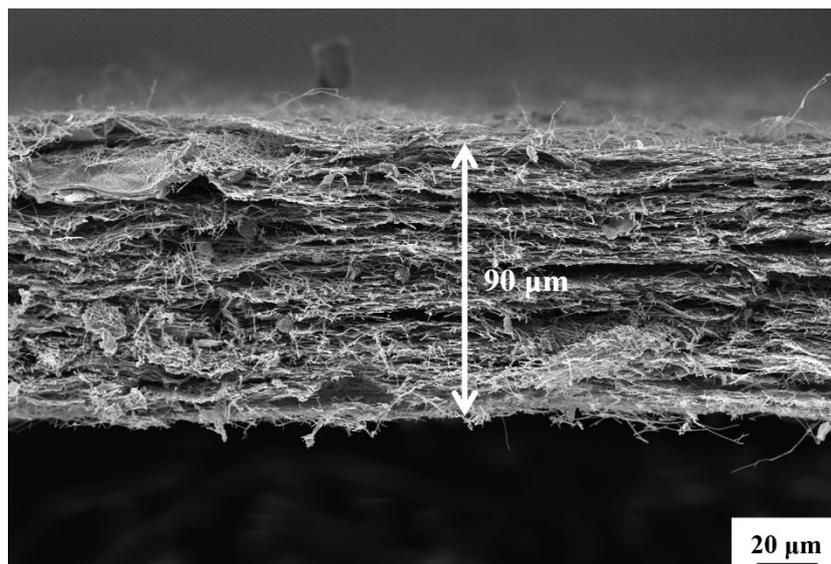


Fig. S4. Cross-sectional morphology of Ti₂Nb₂O₉/CNF film.

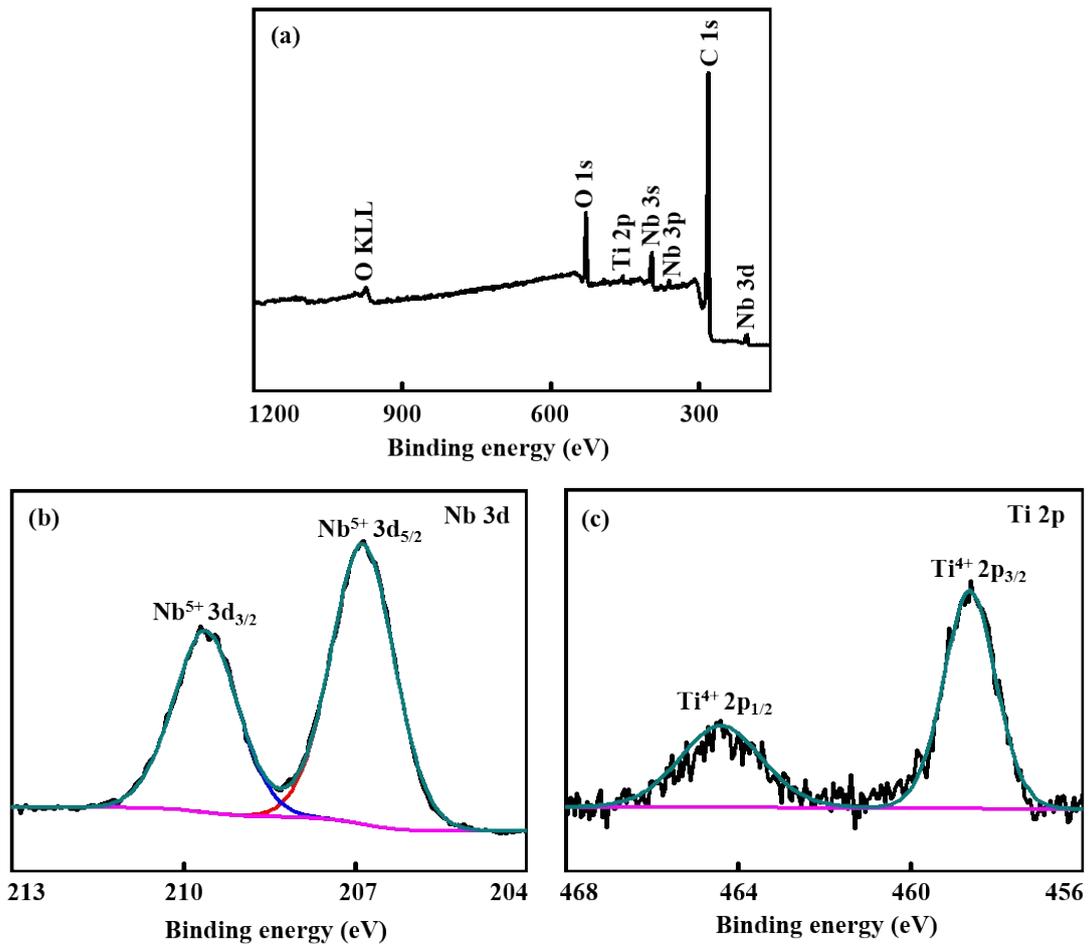


Fig. S5. XPS spectra of Ti₂Nb₂O₉/CNF film: survey spectrum (a), high-resolution Nb 3d (b), and Ti 2p (c).

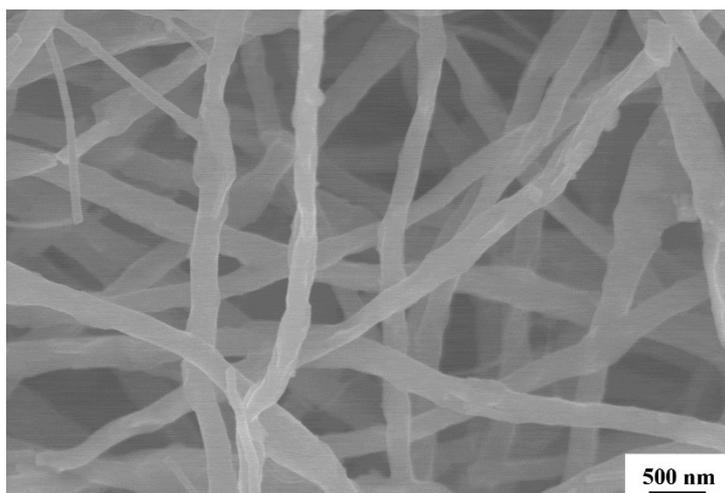


Fig. S6. SEM image of $\text{Ti}_2\text{Nb}_2\text{O}_9/\text{CNF}$ electrode after 2000 cycles at 1 A g^{-1} .

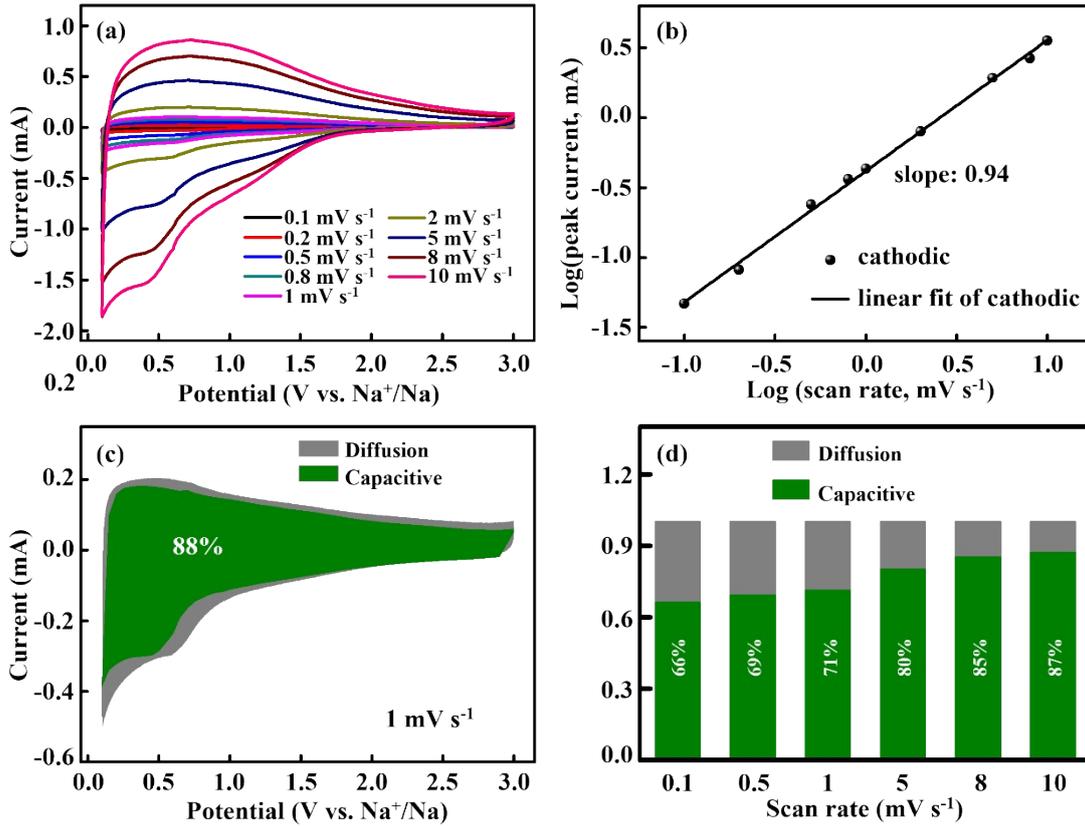


Fig. S7. CV curves at different scan rates (a) and b-value calculated through cathodic scan and peak currents (b) of $\text{Ti}_2\text{Nb}_2\text{O}_9$ electrode, the capacitive and diffusive contribution to the current density at 1 mV s^{-1} of $\text{Ti}_2\text{Nb}_2\text{O}_9/\text{CNF}$ electrode (c), and capacitive-controlled contribution at different scan rates (d) of $\text{Ti}_2\text{Nb}_2\text{O}_9$ electrode.

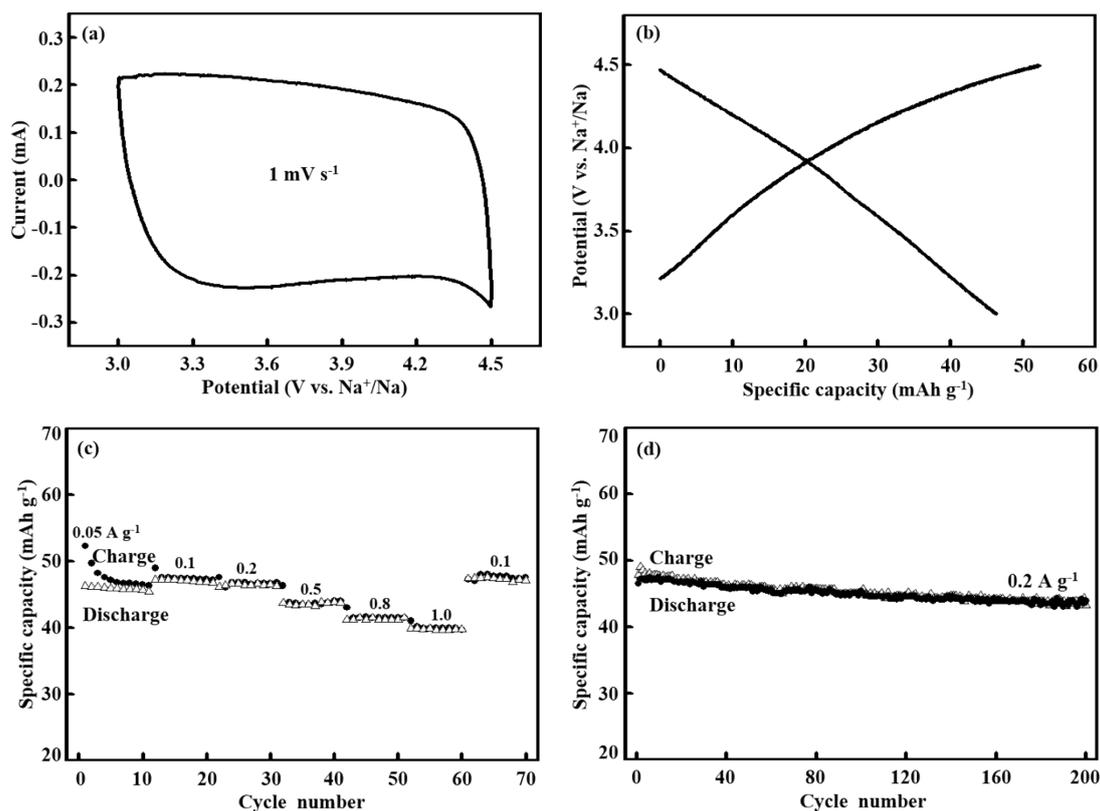


Fig. S8. CV curve at 1 mV s^{-1} (a), galvanostatic charge and discharge curves at 0.05 A g^{-1} between $3.0\text{-}4.5 \text{ V}$ (b), rate capability at different current densities (c), and cycling stability at 0.2 A g^{-1} (d) of AC electrode.

The quasi-rectangular CV curve at 1 mV s^{-1} and linear GCD curves at 0.05 A g^{-1} indicate electric double-layer capacitive behavior of AC electrode. Its specific capacity at 0.05 A g^{-1} is estimated to be 46 mAh g^{-1} , with outstanding rate capability and good cycling stability at 0.2 A g^{-1} ($\approx 95 \%$ after 200 cycles).

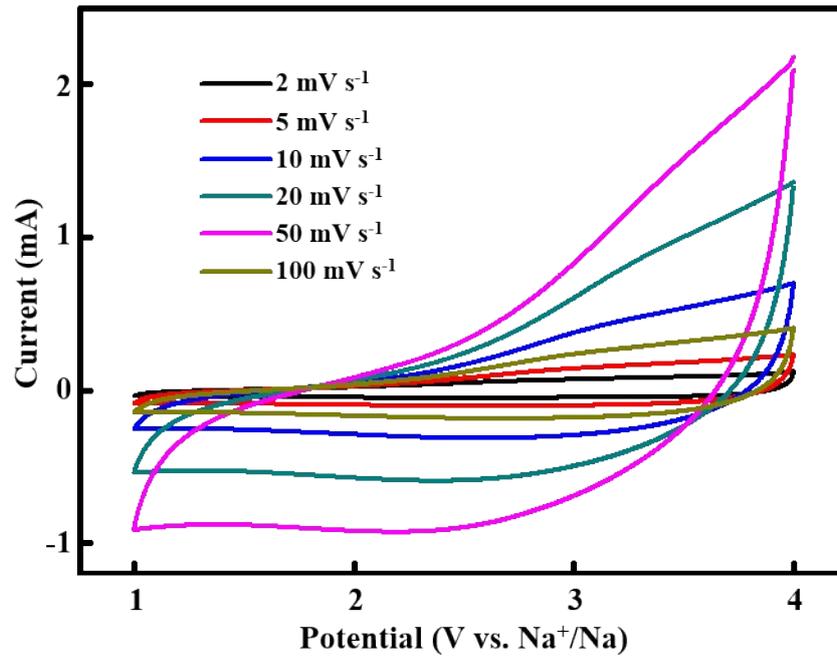


Fig. S9. CV curves at different scan rates from 2 to 100 mV s^{-1} of $\text{Ti}_2\text{Nb}_2\text{O}_9/\text{CNF}/\text{AC}$ SIC.